AN8389S, AN8389SR

4 Ch. Linear Driver IC for CD Player

Overview

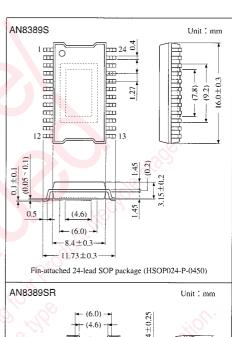
The AN8389S and AN8389SR employ 4 ch. H-bridge system that they are suitable for driving motor or actuator of CD player. Also they employ the surface mounting type package superior in radiation characteristics.

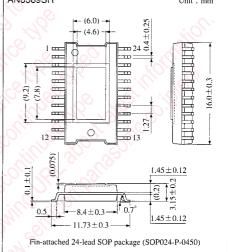
■ Features

- Wide output D-range is available regardless of reference voltage on the system
- 4 ch. BTL Driver built-in. Particularly suitable for driver of actuator or motor of 5 to 20 Ω load.
- Thermal shut down circuit (with hysteresis) built-in
- Control for proper heat of IC by separating the power supplies for signal line and output line.
- Provided with reset output pin
- Shot brake mode

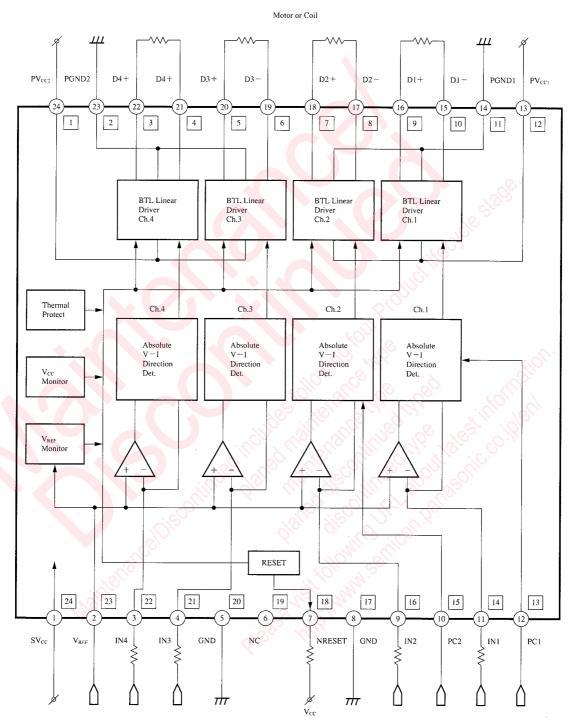
Application

• CD player, CD-ROM, for drive of motor





■ Block Diagram



Pin No. in a circle, \bigcirc is for the AN8389S. Pin No. in a square, \square is for the AN8389SR.

ICs for ECD/

■ Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	
Supply Voltage	V _{cc}	20	V
Supply Current	I_{CC}		mA
Power Dissipation Note)	P _D	2083	mW
Operating Ambient Temperature	T _{opr}	$-20 \sim +75$	$^{\circ}$
Storage Temperature	T_{stg}	$-55 \sim +150$	$^{\circ}$

Note) For surface mounting on $50 \times 50 \times 1.2$ mm glass epoxy board

■ Recommended Operating Range (Ta=25°C)

Parameter	Symbol	Range
Operating Supply Voltage Range	SV _{cc}	4.7V ~ 16V

■ Electrical Characteristics $(T_a = 25 \pm 2^{\circ}C)$

Parameter	Symbol	Condition	min.	typ.	max.	Unit
Total Circuit Current	I _{tot}	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$	10	20	30	mA
Drivers 1 to 4			17.	•		,
Input Offset Voltage	V _{IOF}	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_{L} = 18 \Omega$	-7		7	mV
Output Offset Voltage	V _{OOF}	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_{L} = 18 \Omega$	-50		50	mV
Gain (+)	G+	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_{L} = 18 \Omega$	15.5	18.5	21.5	dB
(+) (Fin-attached 24-lead) Relative Gain	⊿G	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_L = 18\Omega$	=1.0	0	1.0	dB
Limit Voltage (+)	V _L +	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_L = 18 \Omega$	4.95	5.3		V
Limit Voltage (-)	V_{L-}	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_L = 18 \Omega$	9/2	5.3	-4.95	V
Dead Zone Width	V_{DZ}	$PV_{CC1} = PV_{CC2} = SV_{CC} = 8V$ $R_L = 18\Omega$	-10	~0 .	20	mV
Drivers 1 and 2, PC Operation	11, 6,	U. John Ville	D. 73	3.9	•	
Threshold H	V_{PCH}	Medico, NE	1.4			V
Threshold L	V _{PCL}	by grillo yie	2		0.5	V
Reset circuit		10, 60,				
Reset Operation Release Supply Voltage	V _{RST}	· 10 M :	4.2	4.6	4.85	V
Threshold Hysteresis Width	V _{HYS}	is and	0.09	0.17	0.31	V
V _{REF} Detection	V_R		1.85			V
Heat Protection Circuit		So Milk				
Operation Temperature Equilibrium Value Note 1)	T _{THD}		()	(150)	()	$^{\circ}$
Operation Temperature Hysteresis Width Note 11	ΔT_{THD}		(—)	(20)	()	$^{\circ}$

Note 1) Characteristic value in parentheses is a reference value for design but not a guaranteed value.

■ Pin Description

Pin No. Sumbal 1/O DC voltage Bir Davisis						
	AN8389SR	Symbol	I/O	(V _{CC} /8V)	Pin Description	Equivalent Circuit
12	13	PC1	I	0V	PC (power cut) input pin controlling the output of (5) and (6)	12 or 10
10	15	PC2	I	0V	PC (power cut) input pin controlling the output of (1) and (18)	
11	14	IN1	I	2.5V	Error input pin of Driver	Ø Ø
9	16	IN2	I	2.5V	Error input pin of Driver 2	(11) or (9) or 4 or 500 Ω
4	21	IN3	I	2.5V	Error input pin of Driver 3	or \$ 500Ω
3	22	IN4	I	2.5V	Error input pin of Driver	3 # 300 m
7	18	NRESET	0		Reset output pin	7 200 Ω
1	24	SV _{cc}	I	8V	SV_{CC} pin for control circuit of driver, not connected to power V_{CC} pin.	<u> </u>
5 8	20 17	SGND		0V	SGND pin for control circuit of driver	(5) mr (8)
2	23	V _{REF}	I	2.5V	V _{REF} input pin	2
13	12	PV _{CC1}	I	8V	Power V_{CC} pin, supplying the current flowing for output power transistors of $\textcircled{1}$, $\textcircled{1}$, and $\textcircled{1}$	(13) or (24)
24	1	PV _{CC2}	I	8V	Power V_{CC} pin, supplying the current flowing for output power transistors of $(9, 20, 2)$ and (2)	

Note) The pin numbers shown in the equivalent circuit diagram are only for the AN8389S. For the AN8389SR, they must be replaced.

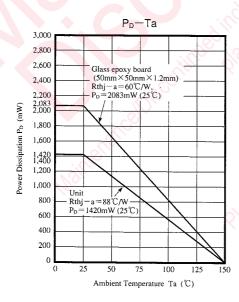


■ Pin Description (Cont.)

Pin AN8389S	No. AN8389SR	Symbol	I/O	DC voltage (V _{CC} /8V)	Pin Description	Equivalent Circuit
14	11	PGND1	I	0V	PGND pin for output transistors of (5), (6), (7) and (8)	14) or 777
23	2	PGND2	I	0V	PGND pin for output transistors of (9, 20, 2) and (2)	23
15	ìO	D1-	0	0V	Reverse rotation output pin of Driver 1	(PVcc) ←
16	9	D1+	0	0V	Normal rotation output pin of Driver 1	
17	8	D2-	0	0V	Reverse rotation output pin of Driver 2	
18	7	D2+	0	0V	Normal rotation output pin of Driver 2	
19	6	D3-	0	0V	Reverse rotation output pin of Driver 3	
20	5	D3+	0	0V	Normal rotation output pin of Driver 3	
21	4	D4-	0	0V	Reverse rotation output pin of Driver 4	19 (5) A 20 (16) or or
22	3	D4+	0	0V	Normal rotation output pin of Driver 4	21 17 ## 22 18

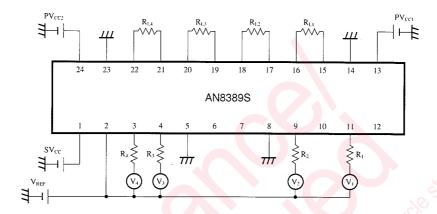
Note) The pin numbers shown in the equivalent circuit diagram are only for the AN8389S. For the AN8389SR, they must be replaced.

Characteristic Curve



■ Cautions for use

AN8389S



When the AN8389S is used, take into account the following cautions and follow the power dissipation characteristic curve.

(1) Load current, IP1 flowing in loads RL1, and RRL2 is supplied through Pin 3.

$$I_{Pl} = \frac{|V_{16-15}|}{R_{L1}} + \frac{|V_{18-17}|}{R_{L2}}$$

(2) Load current, I_{P2} flowing in loads R_{L3} and RR_{L4} is supplied through Pin 2.

$$I_{P2} = \frac{|V_{20-19}|}{R_{L3}} + \frac{|V_{22-21}|}{R_{L4}}$$

(3) Dissipation increase (ΔP_d) inside the IC (power output stage) caused by loads R_{L1} , RR_{L2} , R_{L3} and RR_{L4} is as follows:

$$\begin{split} \Delta P_{d} &= (PV_{CC1} - |V_{16-15}|) \times \frac{|V_{16-15}|}{R_{L1}} + (PV_{CC1} - |V_{18-17}|) \times \frac{|V_{18-17}|}{R_{L2}} \\ &+ (PV_{CC2} - |V_{20-19}|) \times \frac{|V_{20-19}|}{R_{L3}} + (PV_{CC2} - |V_{22-21}|) \times \frac{|V_{22-21}|}{R_{L4}} \end{split}$$

(4) Dissipation increase (△P₂) inside the IC (signal block supplied from Pin①) caused by loads R_{L1}, RR_{L2}, R_{L3} and RR_{L4} is almost as follows:

$$TT = \frac{|V_1|}{R_1} + \frac{|V_2|}{R_2} + \frac{|V_3|}{R_3} + \frac{|V_4|}{R_4}$$

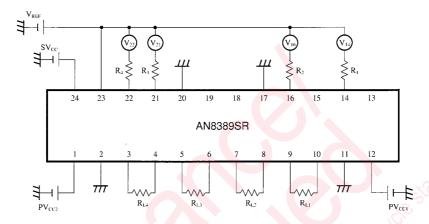
$$\Delta P_{S} = V_{CC} \times IT \times 10 + V_{CC} \times (I_{P1} + I_{P2}) \times 10^{-2}$$

(5) Dissipation increase inside the IC during driver running is $\Delta P_d + \Delta P_s$.



Cautions for use

AN8389SR



When the AN8389SR is used, take into account the following cautions and follow the power dissipation characteristic curve.

(1) Load current, IP1 flowing in loads RL1 and RRL2 is supplied through Pin 2.

$$I_{PI} = \frac{|V_{9-10}|}{R_{L1}} + \frac{|V_{7-8}|}{R_{L2}}$$

(2) Load current, IP2 flowing in loads RL3 and RRL4 is supplied through Pin 1.

$$I_{P2} = \frac{|V_{5-6}|}{R_{L3}} + \frac{|V_{3-4}|}{R_{L4}}$$

(3) Dissipation increase (∠P_d) inside the IC (power output stage) caused by loads R_{L1}, RR_{L2}, R_{L3} and RR_{L4} is as follows:

$$\begin{split} \varDelta P_{d} &= (PV_{CC1} - |V_{9-10}|) \times \frac{|V_{9-10}|}{R_{L1}} + (PV_{CC1} - |V_{7-8}|) \times \frac{|V_{7-8}|}{R_{L2}} \\ &+ (PV_{CC2} - |V_{5-6}|) \times \frac{|V_{5-6}|}{R_{L3}} + (PV_{CC2} - |V_{3-4}|) \times \frac{|V_{3-4}|}{R_{L4}} \end{split}$$

(4) Dissipation increase (△P_S) inside the IC (signal block supplied from Pin⁽²⁾) caused by loads R_{L1}, RR_{L2}, R_{L3} and RR_{L4} is almost as follows:

$$IT = \frac{|V_1|}{R_1} + \frac{|V_2|}{R_2} + \frac{|V_3|}{R_3} + \frac{|V_4|}{R_4}$$

$$\Delta P_{S} = V_{CC} \times IT \times 10 + V_{CC} \times (I_{P1} + I_{P2}) \times 10^{-2}$$

(5) Dissipation increase inside the IC during driver running is $\Delta P_d + \Delta P_s$.

Request for your special attention and precautions in using the technical information and semiconductors described in this book

- (1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.
- (2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.
- (3) The products described in this book are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).
 - Consult our sales staff in advance for information on the following applications:
 - Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
 - · Any applications other than the standard applications intended.
- (4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
- Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
- (7) This book may be not reprinted or reproduced whether wholly or partially, without the prior written permission of our company.

20080805